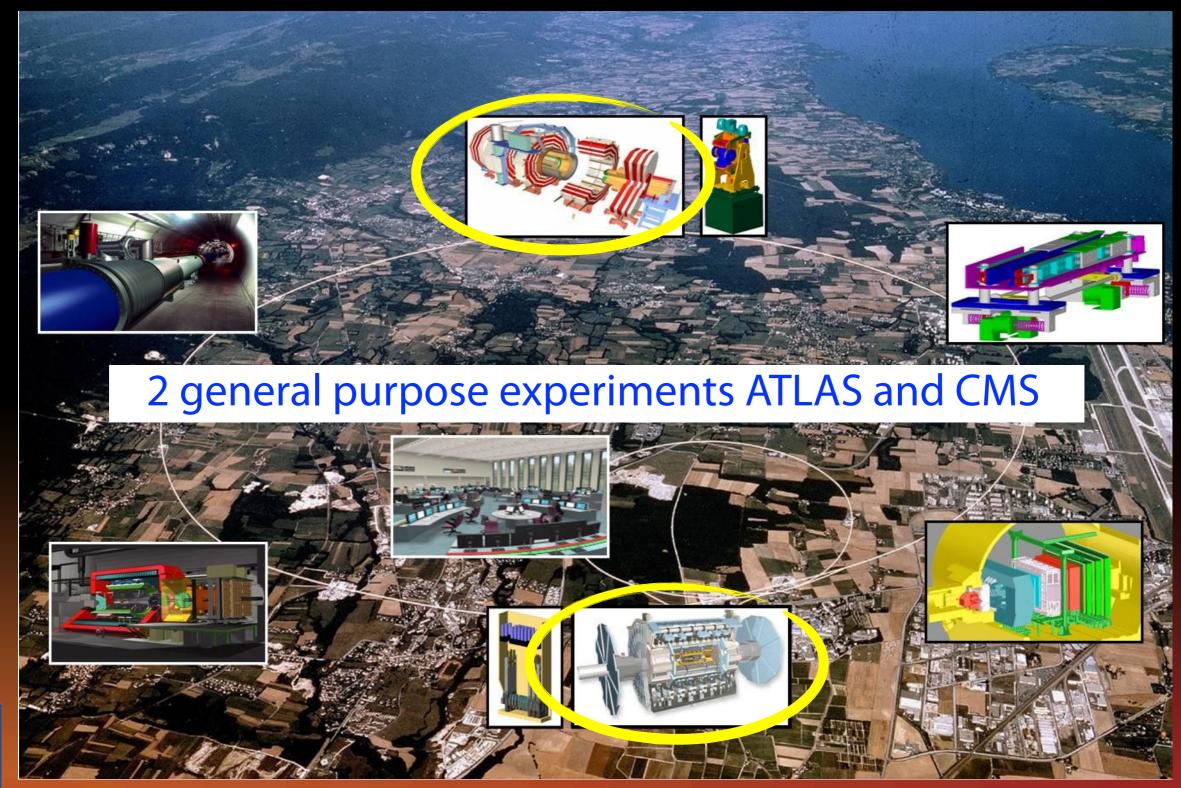


Introduction: the LHC and the Experiments



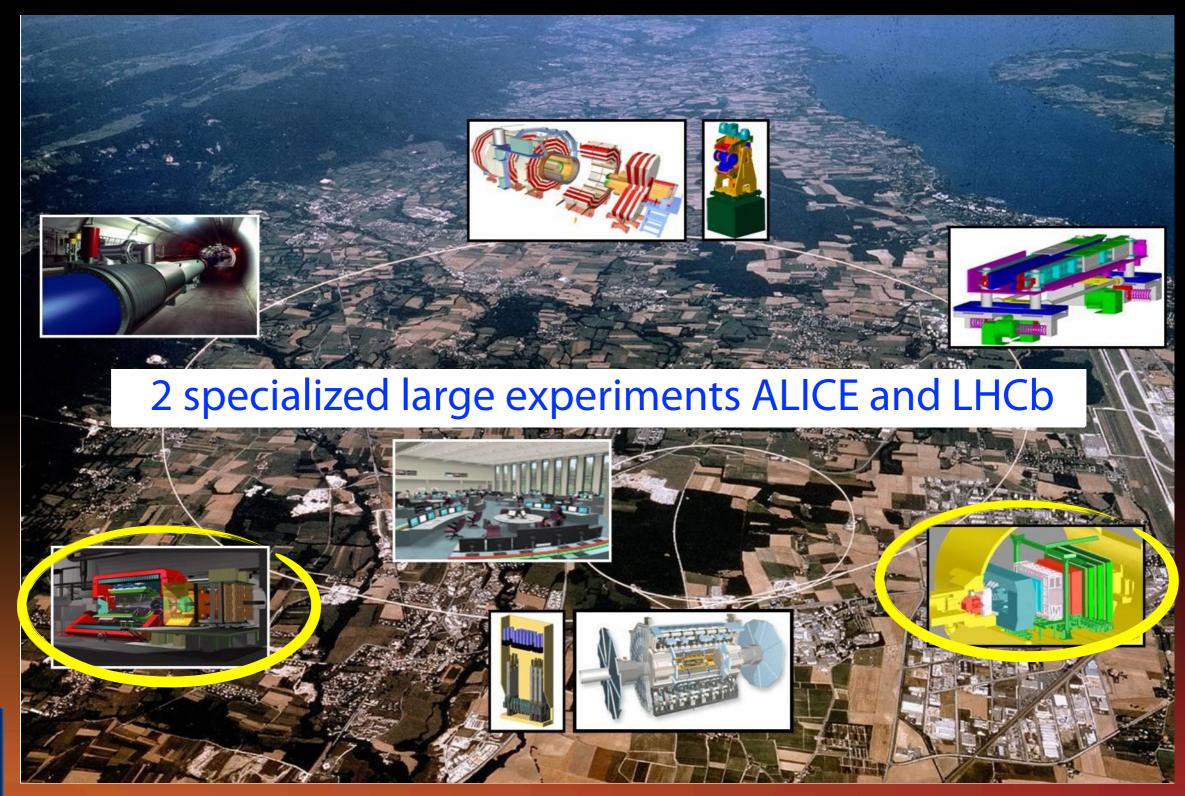


Introduction: the LHC and the Experiments

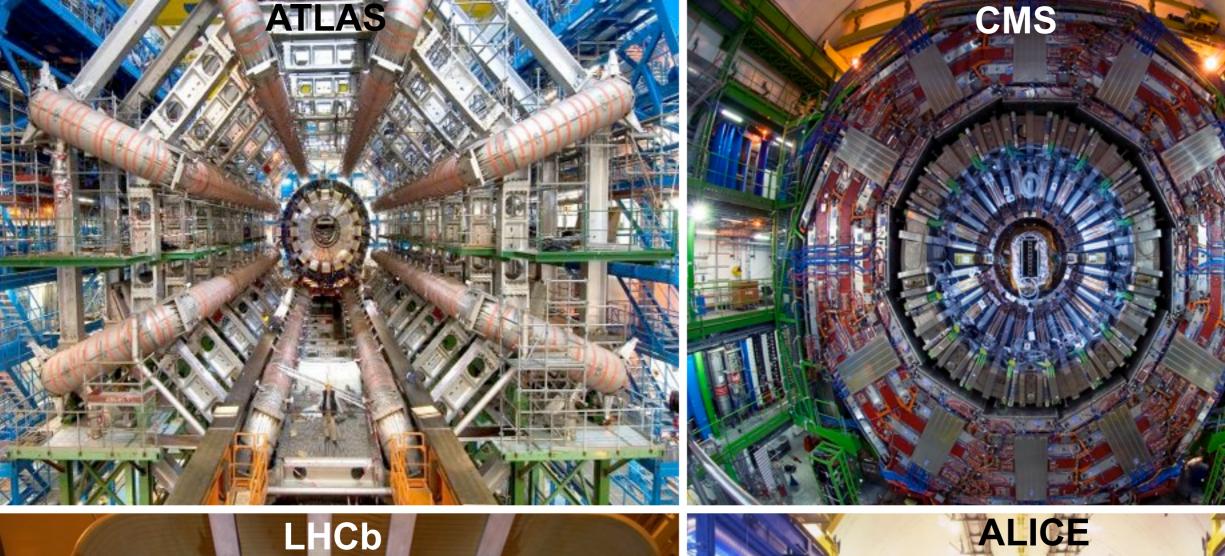




Introduction: the LHC and the Experiments











Outline of Part 2

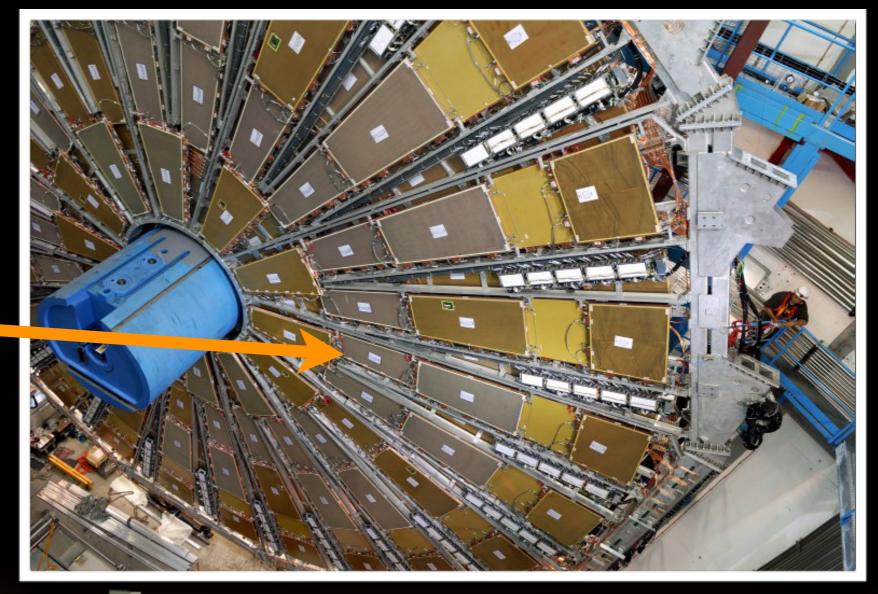
- give an overview of the LHC detectors
 - → inner tracking and as well some words on the muon systems
- tracking detectors
 - → discuss constraints, roles and design choices
- detector technologies and their applications
 - → semiconductor trackers
 - → drift tube detectors

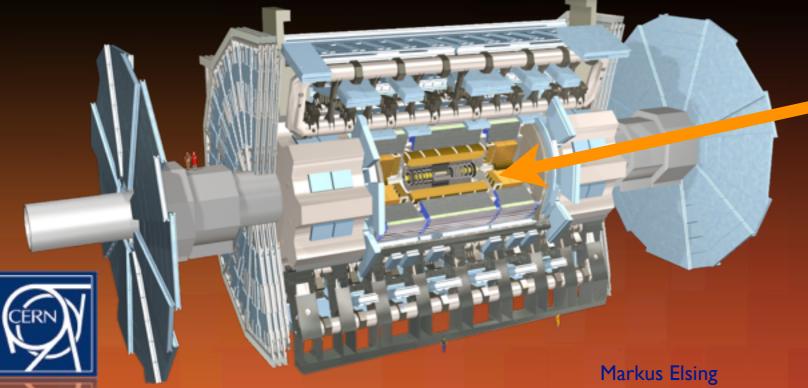


ATLAS

from the outside, all one sees are muon chambers

tracking of muons in toroid field



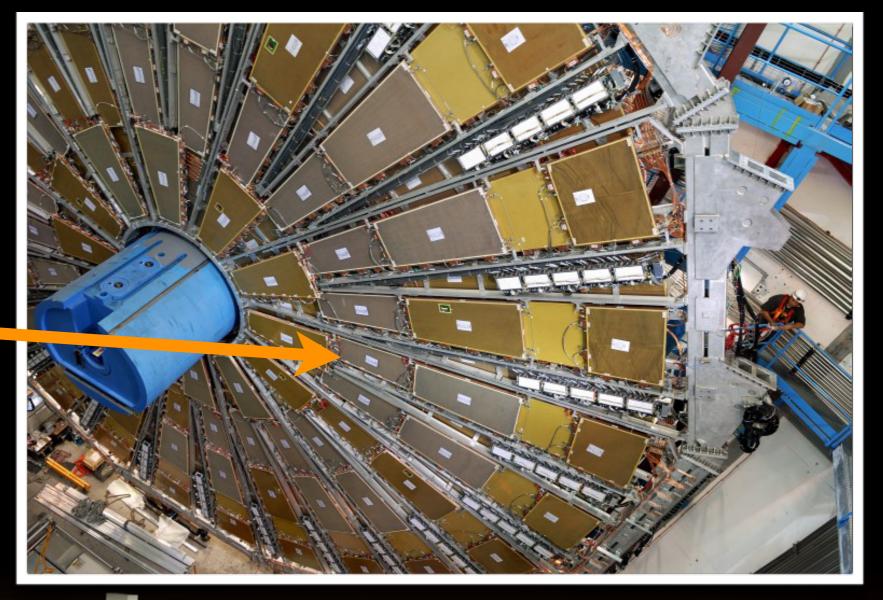


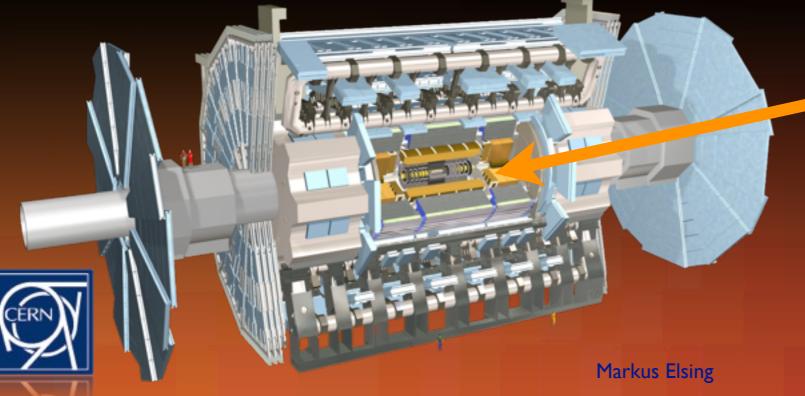
- → most particles are absorbed in the calorimeters, which measure their energy
- → not subject of these lectures

ATLAS

from the outside, all one sees are muon chambers

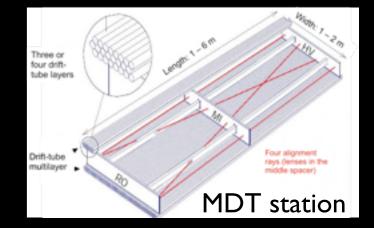
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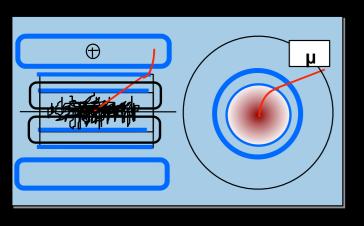


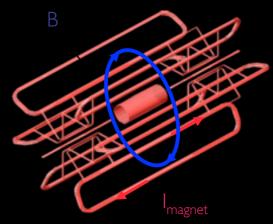


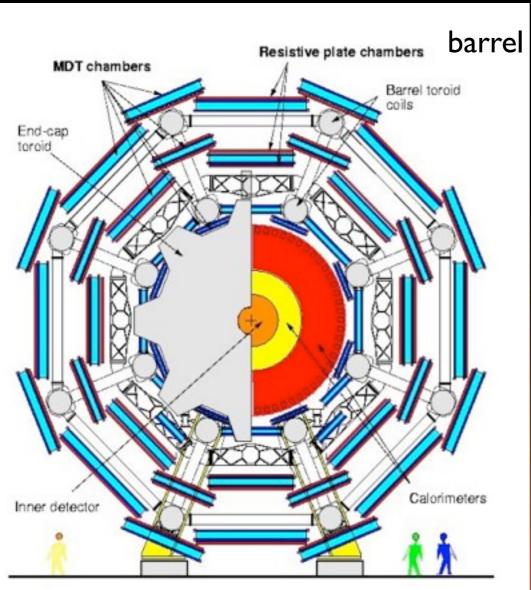
- most particles are absorbed in the calorimeters, which measure their energy
- → not subject of these lectures
- let' have a brief look at the muon systems
 - → ATLAS and CMS

ATLAS Muon Spectrometer

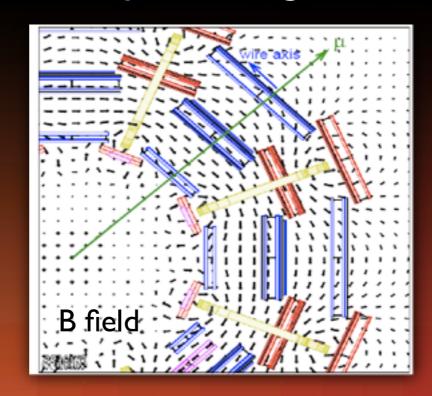


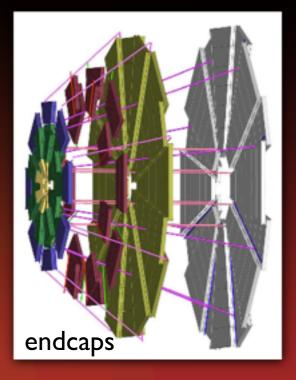




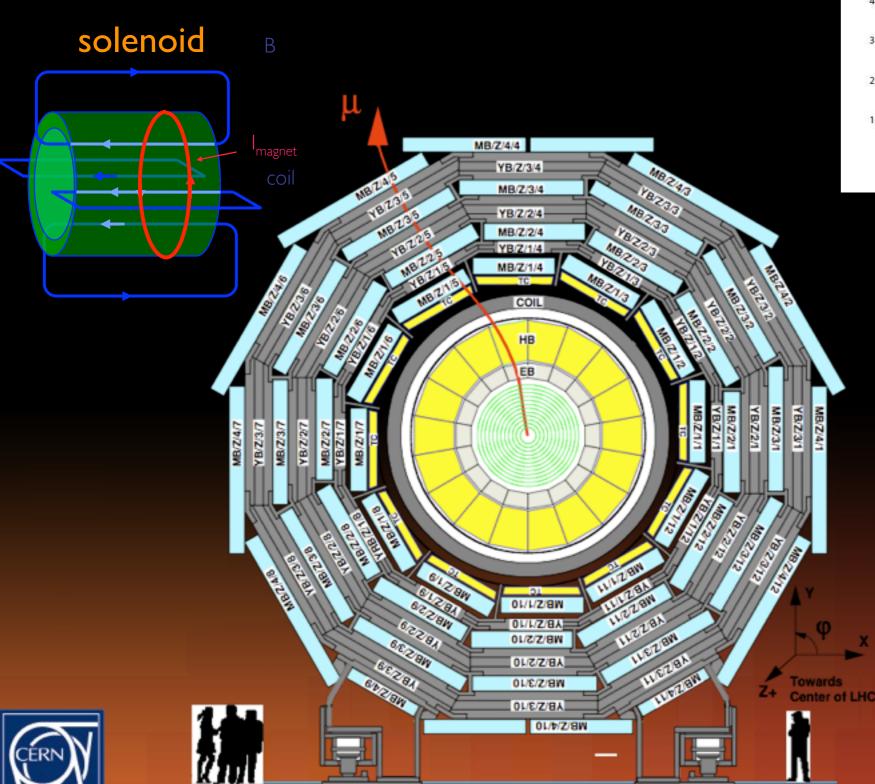


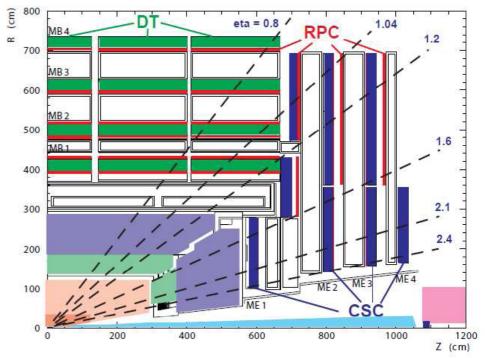
- a huge system
 - → 4 different technologies (MDT,CSC,RPC,TGC)
 - \rightarrow large area (10.000 m²)
 - → many channels (1 M)
- toroid field configuration
 - → large magnetic field variations in toroid
 - → field 4 Tesla near coils
- optical alignment system





CMS Muon System

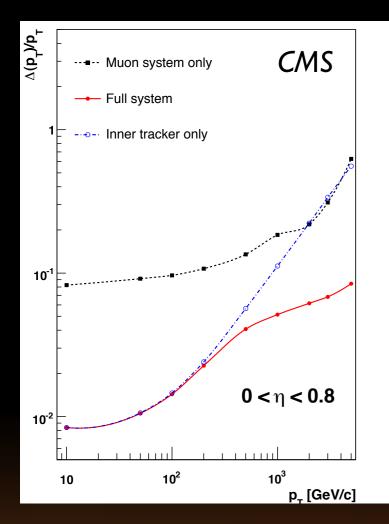


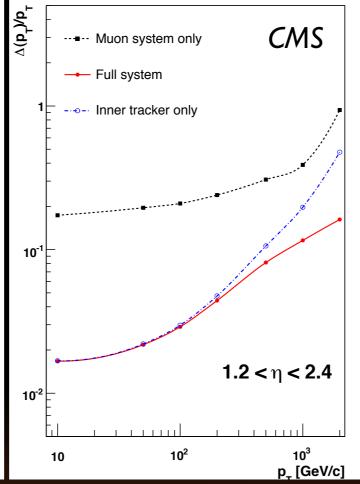


Muon Drift Tubes

- → magnetic field return in iron yoke of solenoid
- \rightarrow combine with precise p_T measurement in Tracker
- Cathode Strip Chambers
 - → in the endcaps
- Resistive Plate Chambers

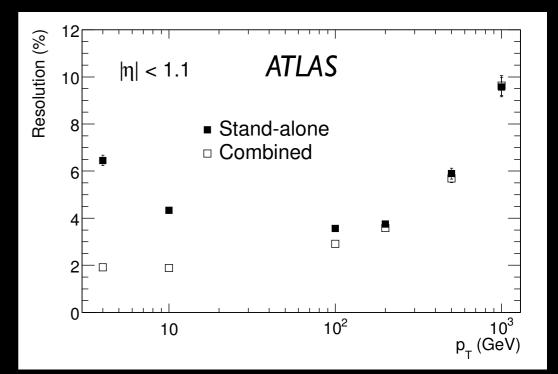
Expected Momentum Resolution

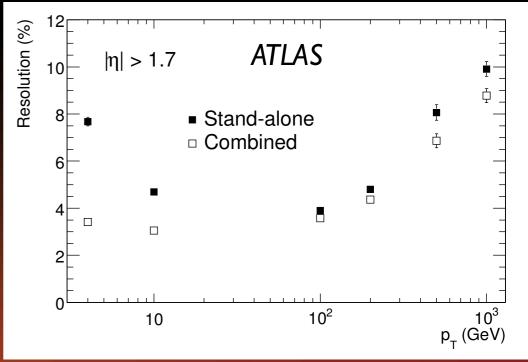




comparable performance

- → CMS benefits from good Inner Tracker resolution
- ⇒ in ATLAS Muon Spectrometer dominates at high p_T
- → ATLAS has slightly larger η coverage

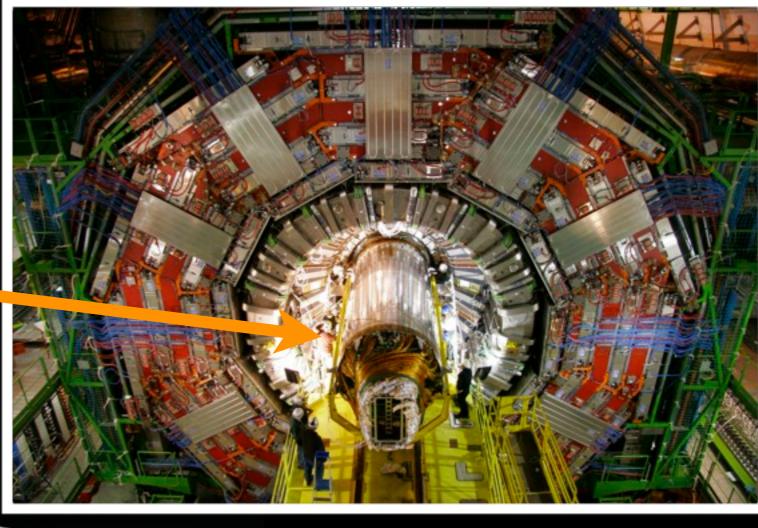






CMS

 in the following will concentrate on the central trackers



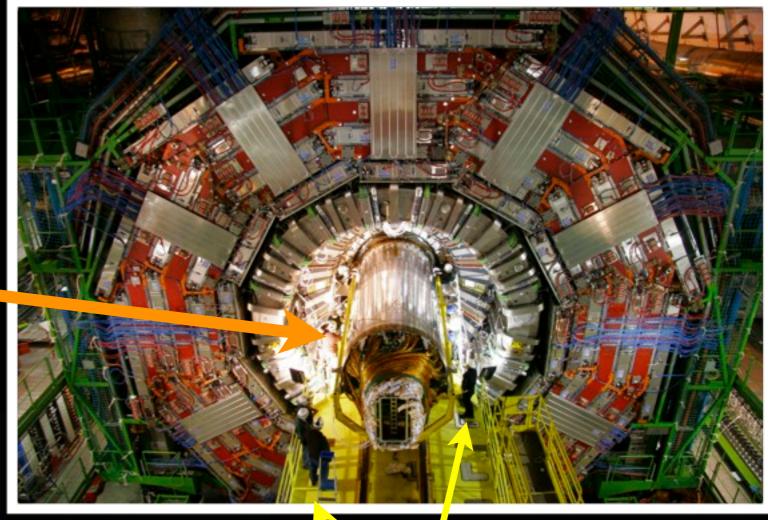




Total weight 12500 t, Overall diameter 15 m, Overall length 21.6 m, Magnetic field 4 Tesla

CMS

 in the following will concentrate on the central trackers





...like for sure they did as well



Total weight 12500 t, Overall diameter 15 m, Overall length 21.6 m, Magnetic field 4 Tesla

Constraints on Tracking Detectors

- high occupancy, high radiation dose, high data rate
 - → at full design luminosity more than 20 interactions per pp bunch crossing
 - more than a 1000 charged particles in tracker, every 25ns.
 - → even higher multiplicity in central Pb-Pb collisions
 - with >10000 charged particles in trackers
 - → design for 10¹⁵ neq (neutron equivalent) for innermost layers (10 year lifetime)

• tension...

- → minimize material for most precise measurements and to minimize interactions before the calorimeter
- ⇒ increasing **sensor granularity** to reduce occupancy
 - increase number of electronics channels and heat load
 - more material

technology choices

- ⇒ silicon detectors, usually pixels for vertexing, and strips for tracking
 - good spatial resolution, high granularity, fast signal response
 - thin detector gives a large signal
- ⇒ can be complemented by gas detectors further away from vertex



Additional Roles of Tracker at LHC

- tracker also contribute to particle identification (PID)
 - → use dedicated detectors to distinguish different particle types
 - Transition Radiation detectors also contribute to tracking
 - Ring Imaging Cherenkov detectors
 - time of flight
- match tracks with showers in the calorimeter
 - → identify electrons from characteristic shower shape
- match central tracks with muon chamber segments
 - muon chamber information improves muon momentum measurement



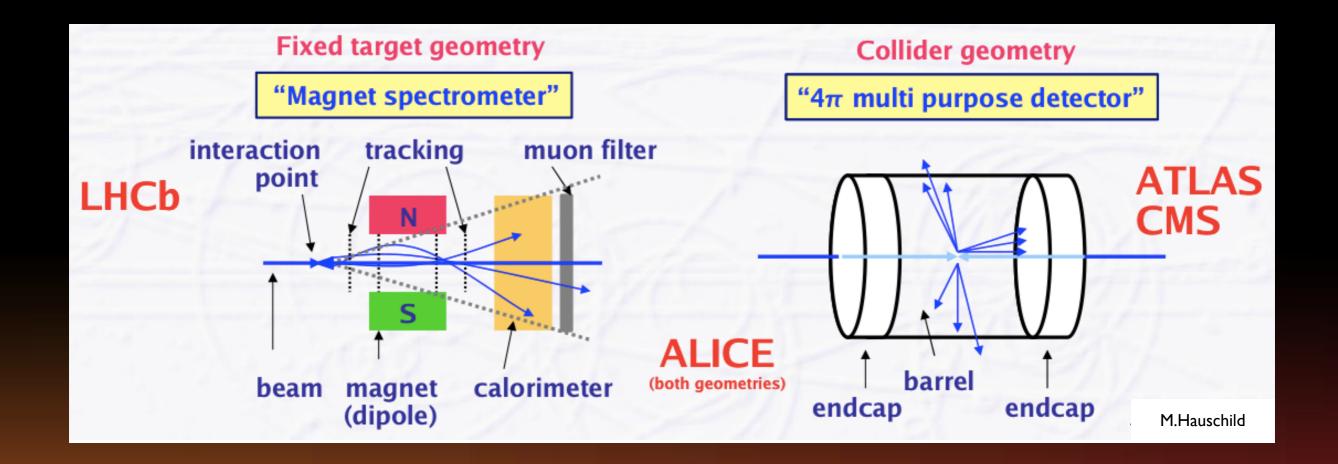
Overall Design Choices

- ATLAS and CMS are general purpose detectors
 - \Rightarrow central tracker covers $|\eta| < 2.5$ (polar angle expressed as pseudorapidity: $\eta = -\ln \tan (\Theta/2)$)
- ALICE optimized for heavy ions, high occupancy
 - \rightarrow tracker restricted to $|\eta|$ < 0.9, plus forward muons
- all three are symmetric about the interaction point
 - → solenoid magnet providing uniform magnetic field parallel to the beam direction
 - → ATLAS Muon Spectrometer is in field of 3 toroid magnets
- LHCb beauty-hadron production in forward direction
 - → despite the different geometry, design is driven by the same principles to give optimal performance
 - tracker is not in a magnetic field, tracks are measured before and after a dipole magnet



Overall Design Choices

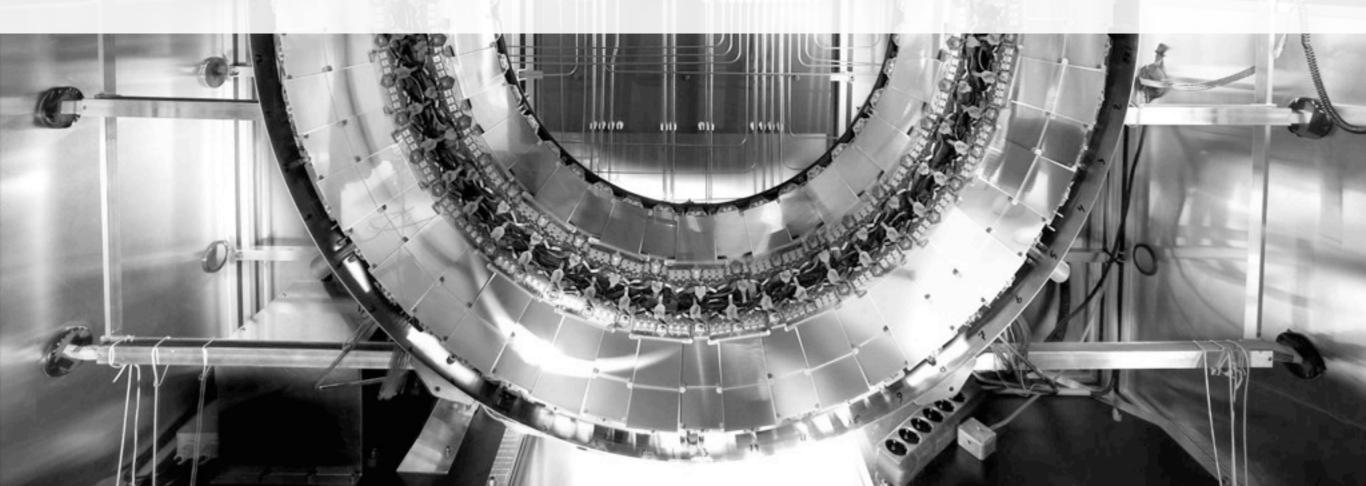
- layout of the tracking detectors
 - → follow the typical geometry of fix target and collider experiments





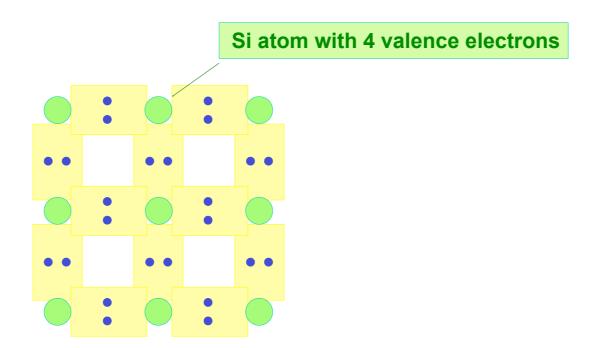


Semiconductor Trackers





doping of silicon crystal semiconductors:





doping of silicon crystal semiconductors:

"excess" electron

donor impurity examples: As, P



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"excess" electron

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Si atom with 4 valence electrons

"excess" hole

acceptor impurity examples: B, Al, In



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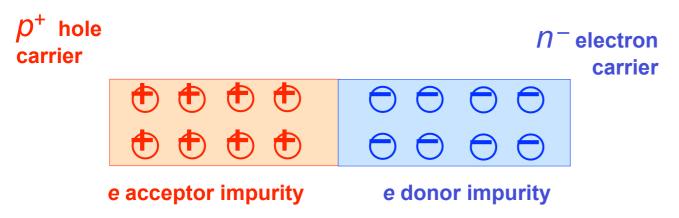
donor impurity examples: As, P

Si atom with 4 valence electrons

"excess" hole

acceptor impurity examples: B, Al, In

p–*n* junction



- p doping adds electro-phile atoms
- n doping adds electro-phobe atoms



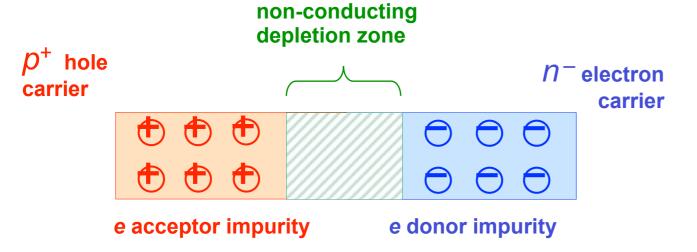
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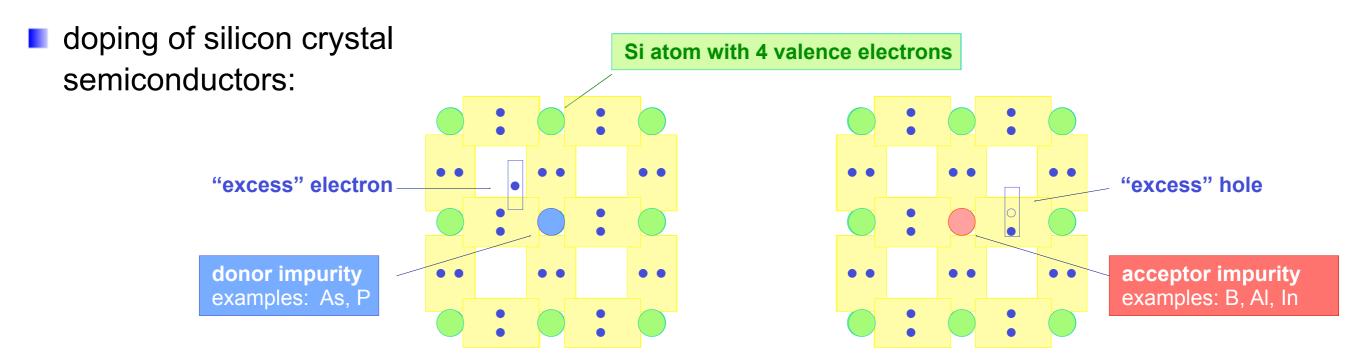
acceptor impurity examples: B, Al, In

p–*n* junction

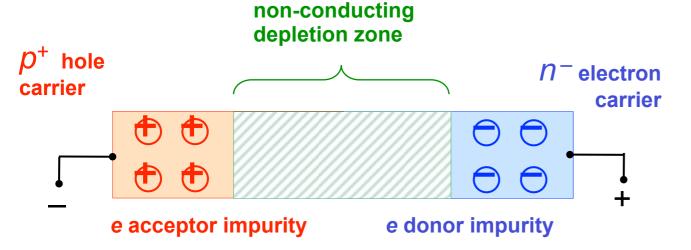


- in the junction zone, electron-hole pairs recombine creating depletion
 - the potential barrier in the junction counter-weighs the doping potential





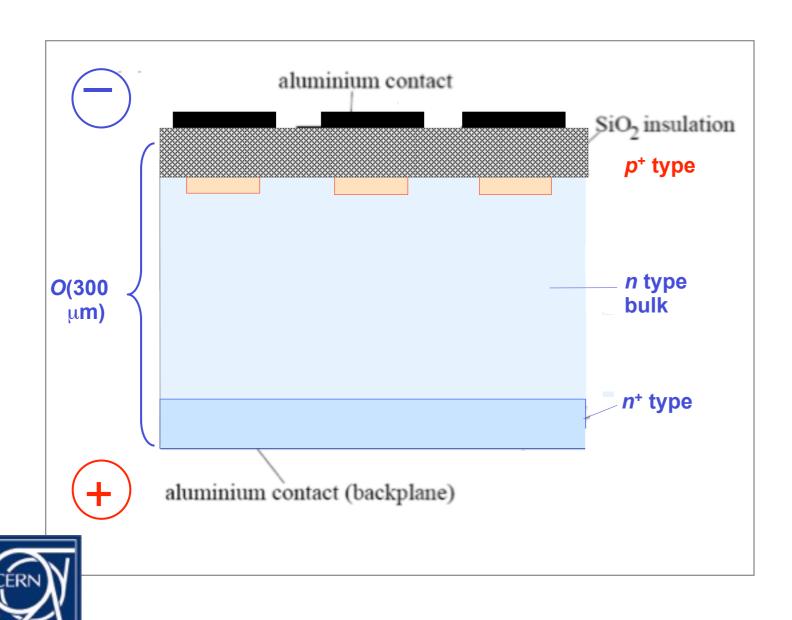
reverse bias *p*–*n* junction



- the reversed bias voltage increases the potential barrier in the depletion zone, enhancing its resistance
- minimal current across the junction

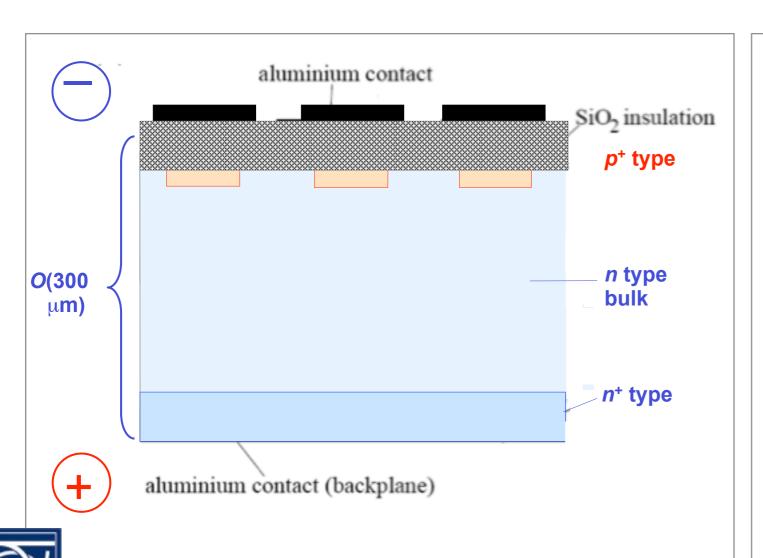


The *p*–*n* Junction as a Tracking Detector



The *p*–*n* Junction as a Tracking Detector

- thin ($\sim \mu$ m), highly doped p^+ ($\sim 10^{19}$ cm $^{-3}$) layer on lightly doped n ($\sim 10^{12}$ cm $^{-3}$) substrate
- high mobility of charge carriers in Si allows fast charge collection (~5 ns for electron)
- high Si density & low electron—hole creation potential (3.6 eV compared to ~36 eV for gaseous ionization) allows use of very thin detectors with reasonable signal

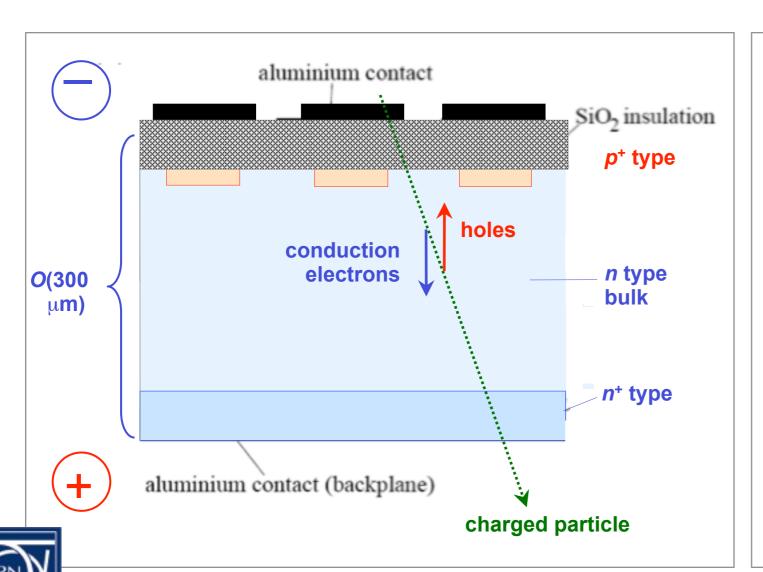


schema of silicon microstrip sensor

- reverse bias: backplane set to positive voltage (< 500 V)</p>
- a traversing charged particle ionizes silicon, creating conduction electrons and holes that induce a measurable current by drifting to electrodes
- metal-semiconductor transition forms charge (Schottky) barrier similar to *p*–*n* junction. Highly doped *n*⁺ layer reduces width of potential barrier and hence resistance

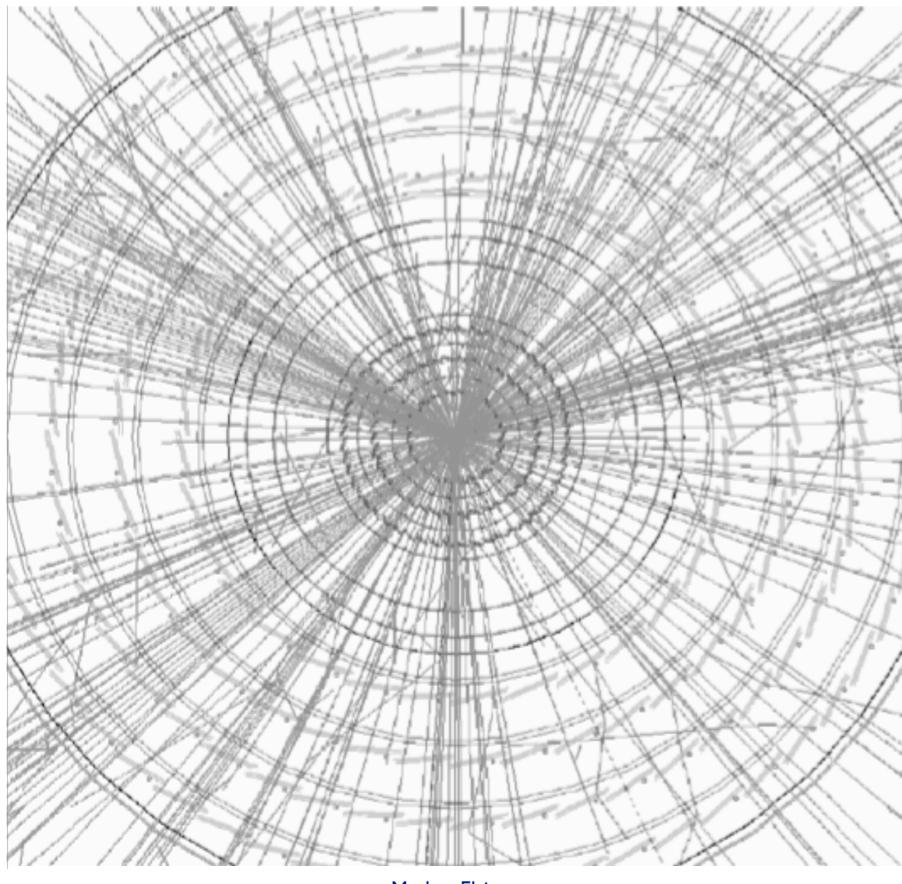
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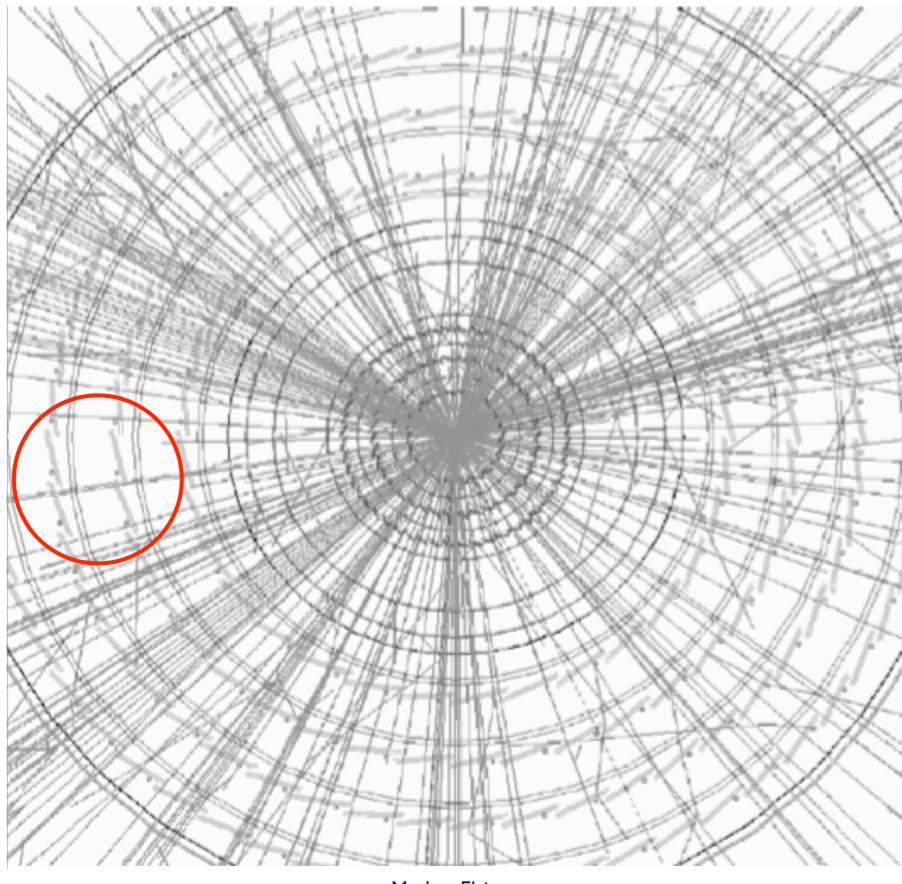
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Markus Elsing

17



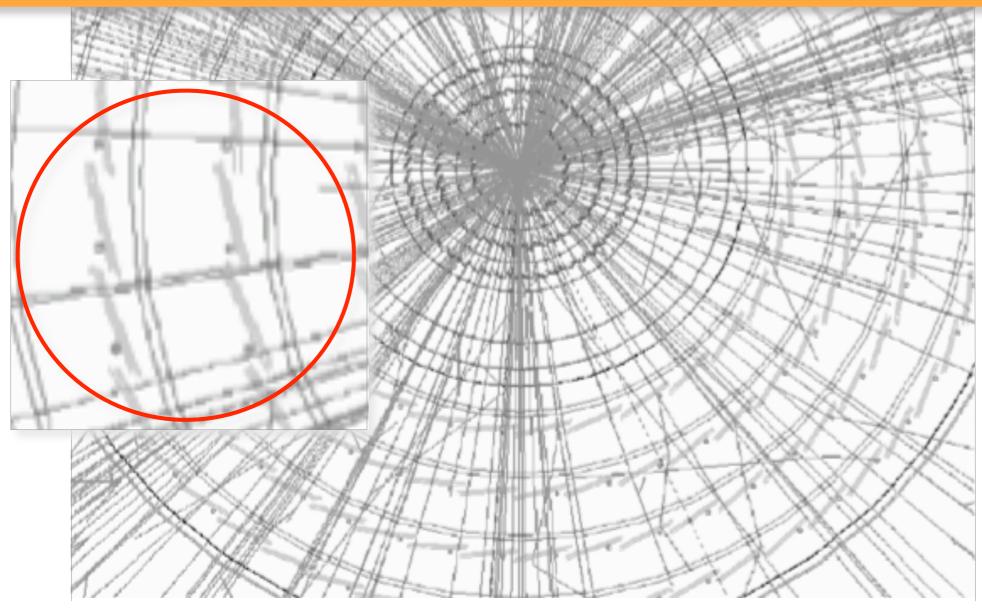


Markus Elsing

17

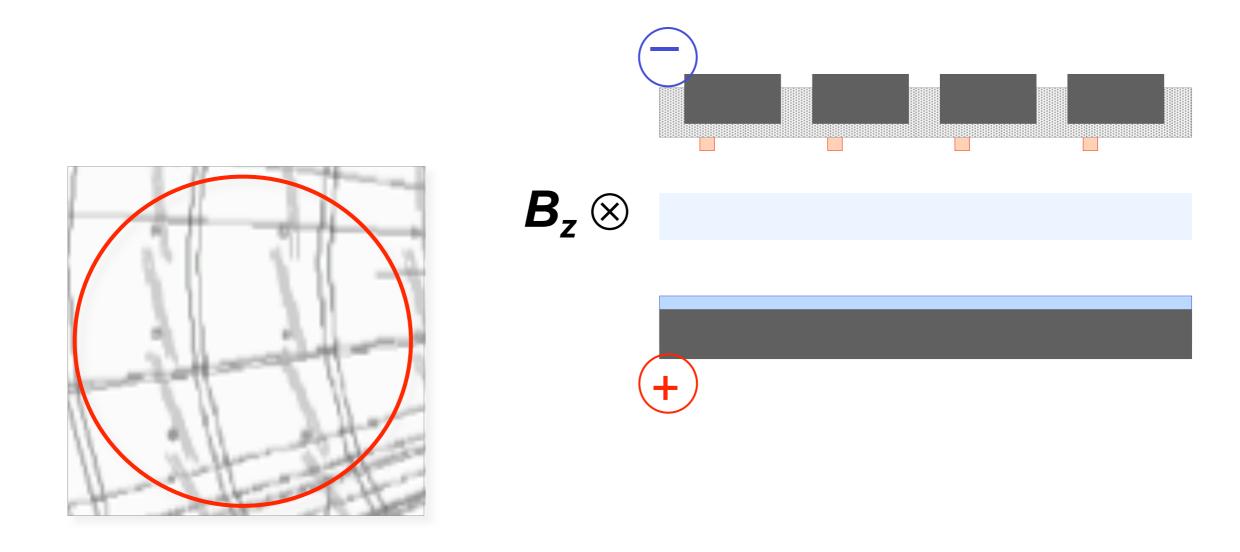
Did you notice?

Classical electromagnetism at play!





- the sensors are tilted relative to the pointing axis: SCT (11°) and Pixel (-20°) (*)
 - the charges traveling through the Si substrate are deviated by 2T B field (Hall effect)

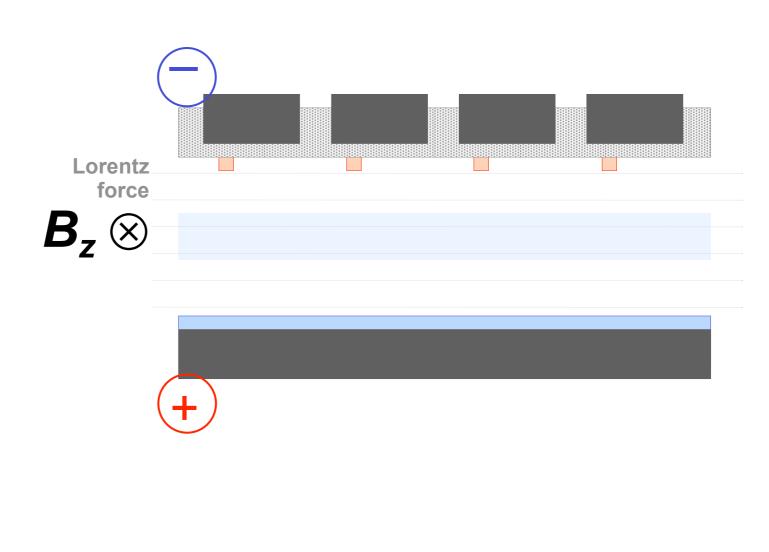




(*) The actual Pixel and SCT Lorentz angles are 4° and 12° (no irradiation), and with opposite signs. The tilts chosen are due to technical reasons.

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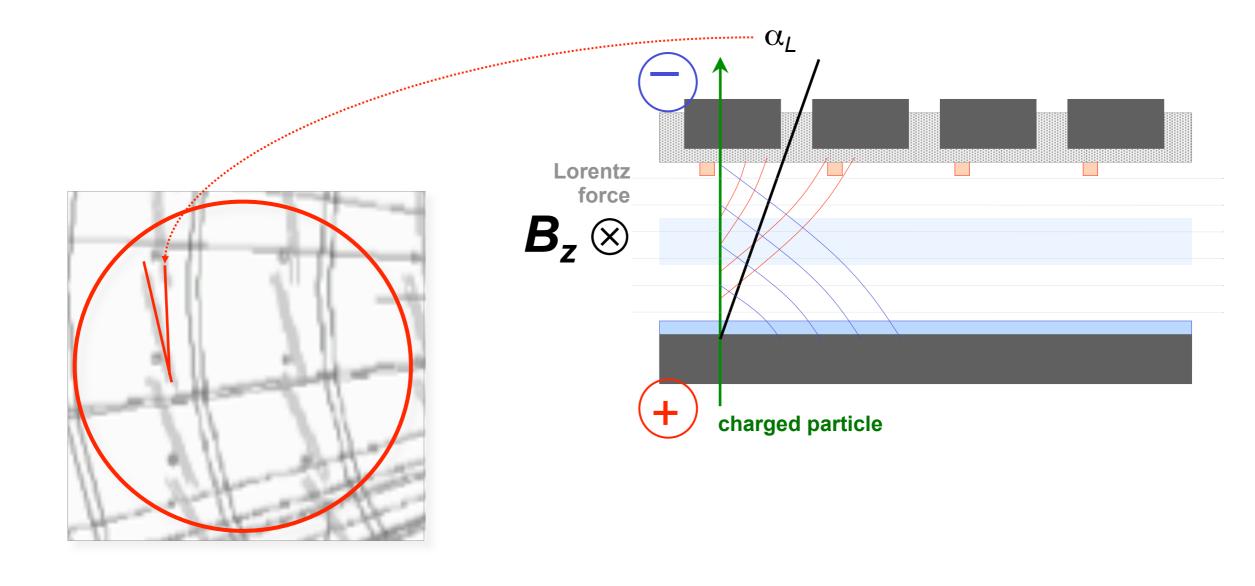






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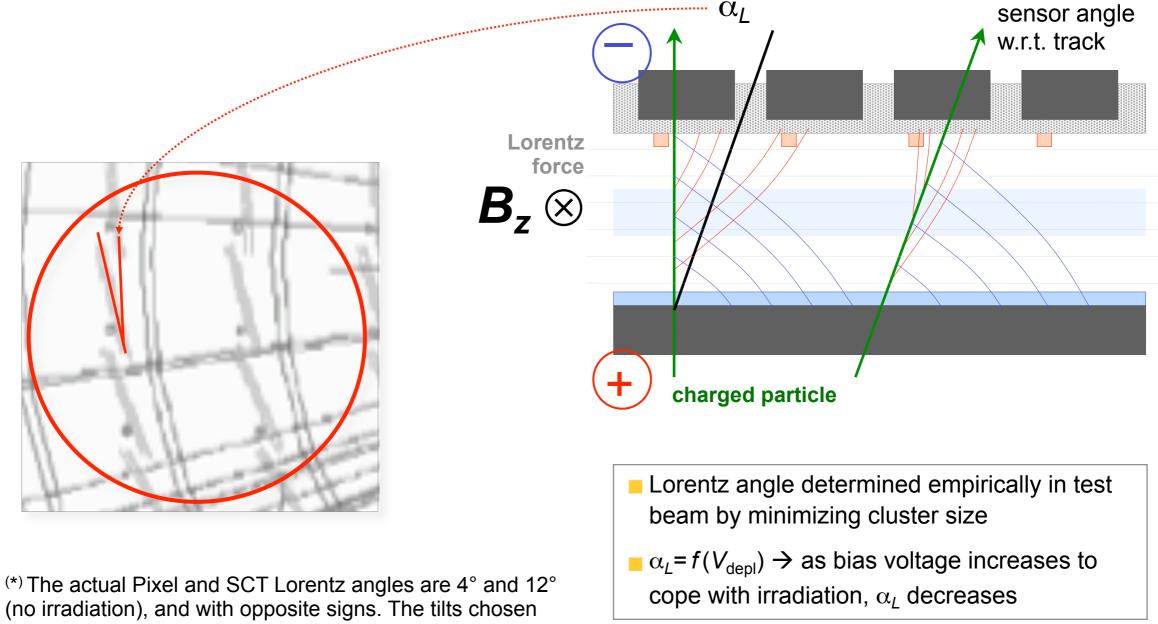
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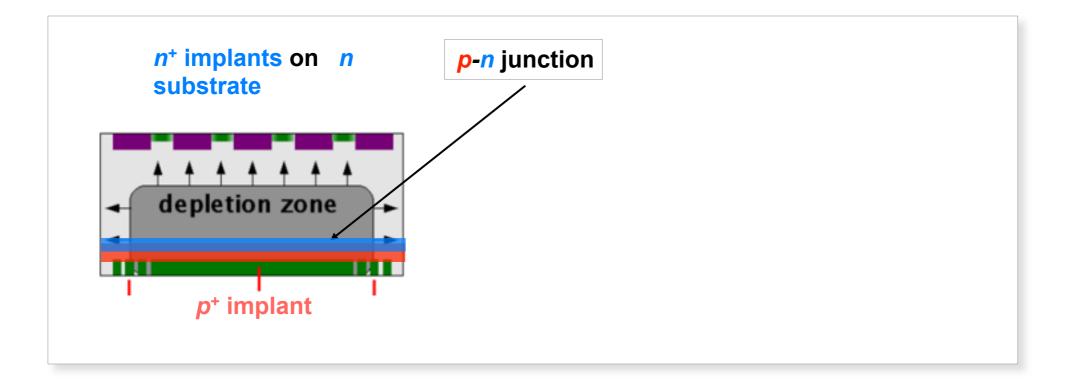
are due to technical reasons.

Pixel Sensors in Radiation Environment

- non-ionizing energy loss (NIEL) from irradiation causes irreversible Si lattice damage
 - increase of leakage current (linear), effective *p* doping, trapping of signal charge
 - "type inversion" of the bulk

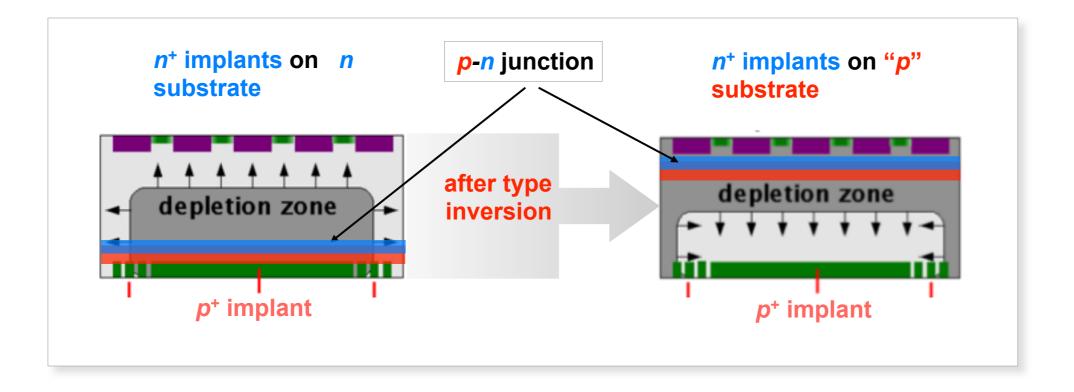


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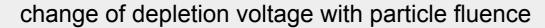


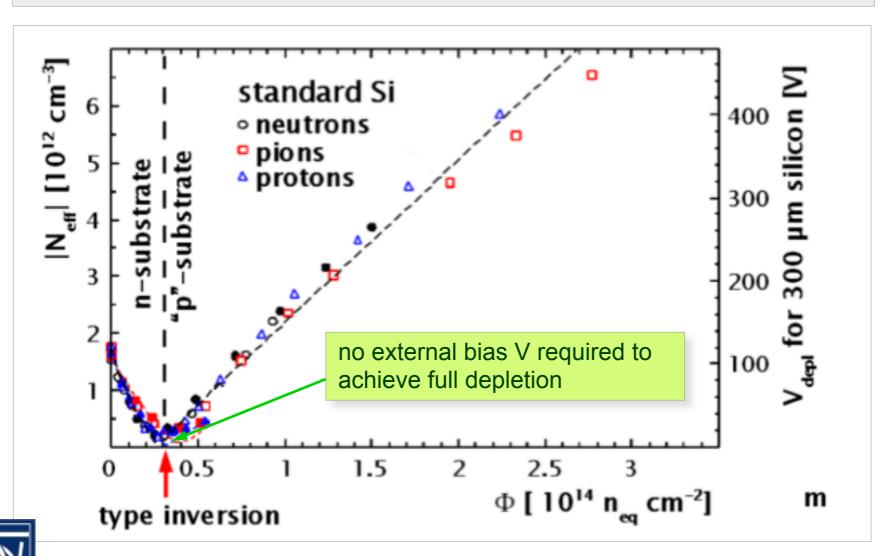
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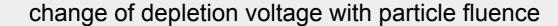


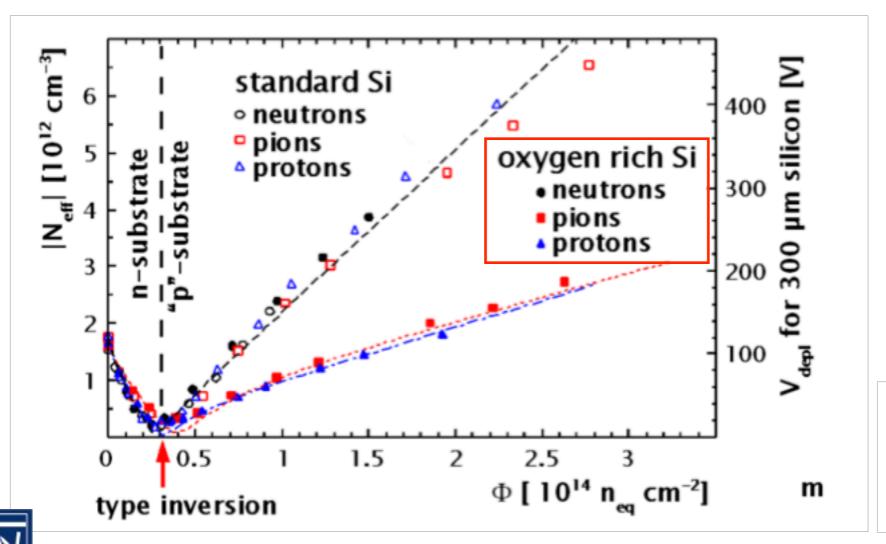
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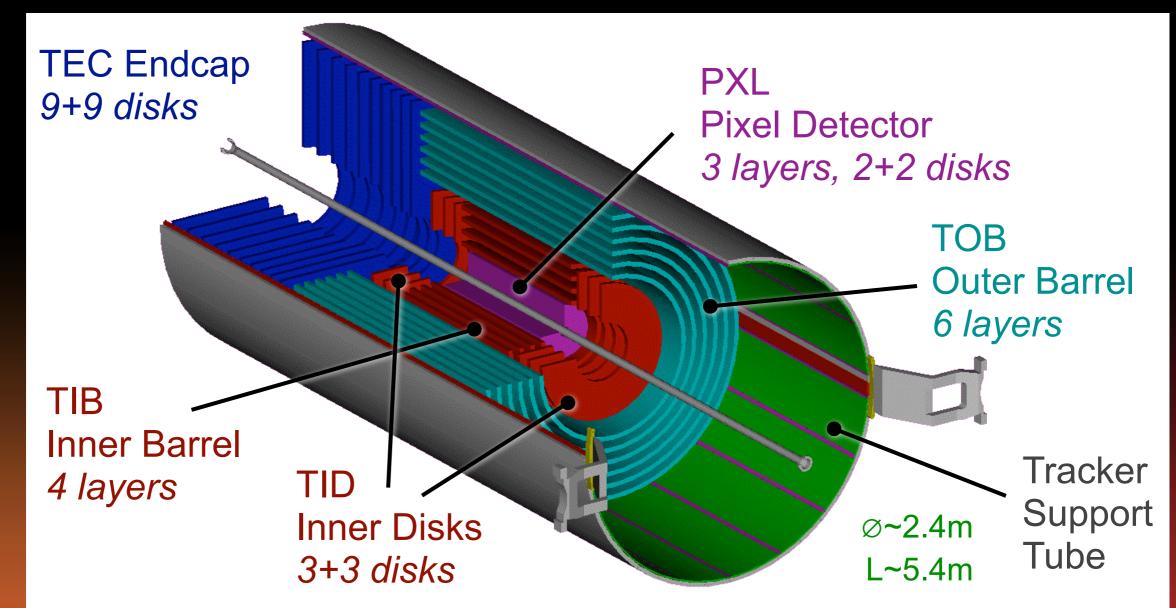


Si oxygenation: keeps required bias voltage for full depletion within operational 600 V for ~10 yrs

CMS Tracker

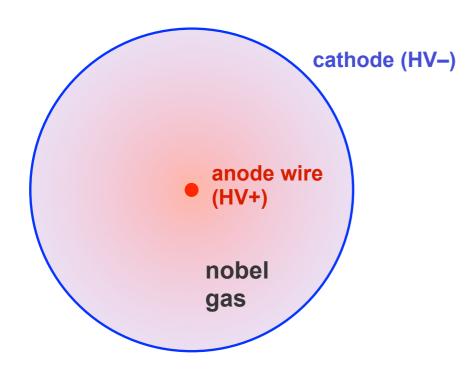
- largest silicon tracker ever built
 - → Pixels: 66M channels, 100x150 μm² Pixel
 - Si-Strip detector: ~23m³, 210m² of Si area, 10.7M channels





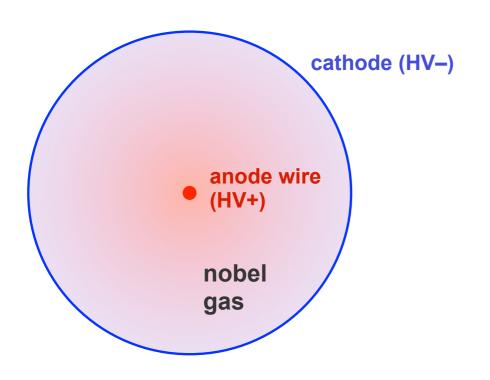


classical detection technique for charged particles based on gas ionization and drift time measurement





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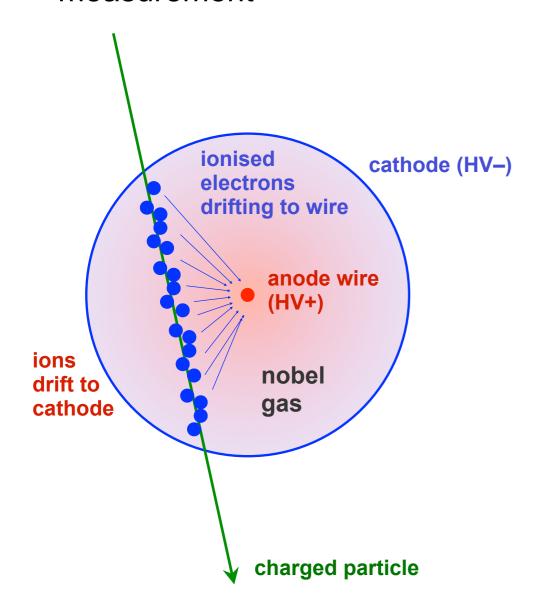


- drift tubes used in muon systems and ATLAS TRT
- primary electrons drift towards thin anode wire
- charge amplification during drift ($\sim 10^4$) in high *E*-field in vicinity of wire: $E(r) \sim U_0 / r$
- signal rises with number of primary e's (dE/dx)
 [signal dominated by ions]
- macroscopic drift time: $v_D/c \sim 10^{-4} \rightarrow \sim 30 \text{ ns/mm}$
- determine v_D from difference between signal peaking time and expected particle passage
- spatial resolution of O(100 μm)



TRT: Kapton tubes, $\emptyset = 4 \text{ mm}$ **MDT:** Aluminium tubes, $\emptyset = 30 \text{ mm}$

classical detection technique for charged particles based on gas ionization and drift time measurement

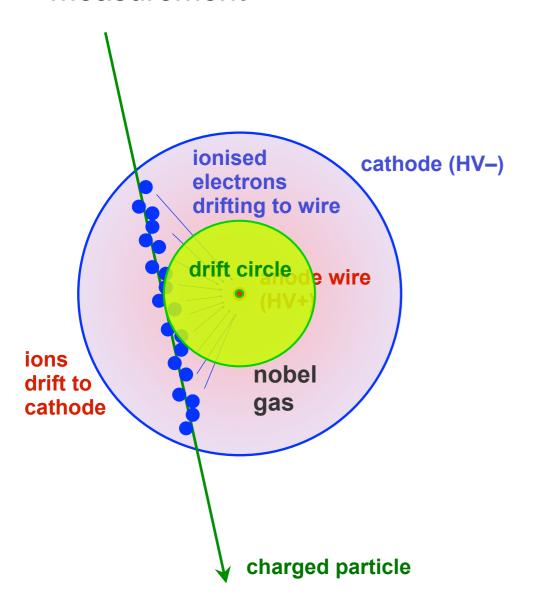


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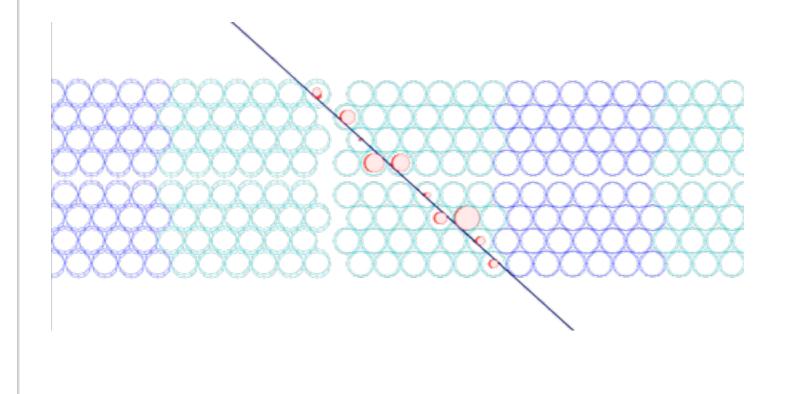
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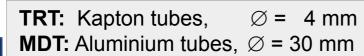


classical detection technique for charged particles based on gas ionization and drift time measurement



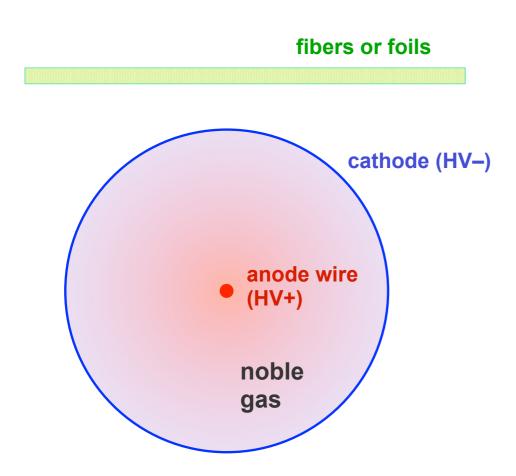
example: segment in muon drift tubes reconstruction from measured drift circles (left-right ambiguity)





Combining Tracking with PID: the ATLAS TRT

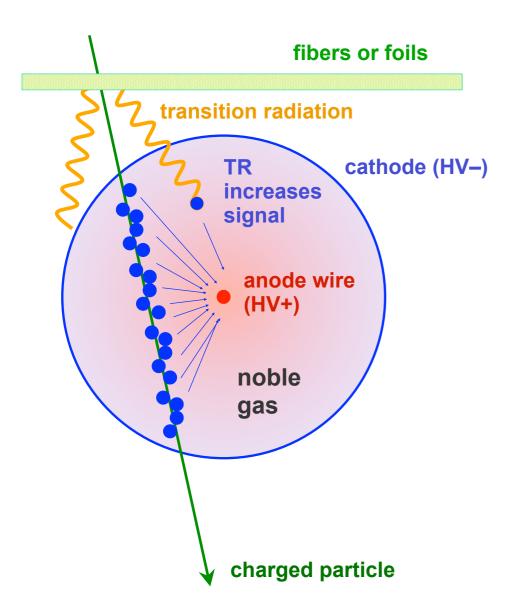
 \bullet e/π separation via transition radiation: polymer (PP) fibers/foils interleaved with drift tubes





Combining Tracking with PID: the ATLAS TRT

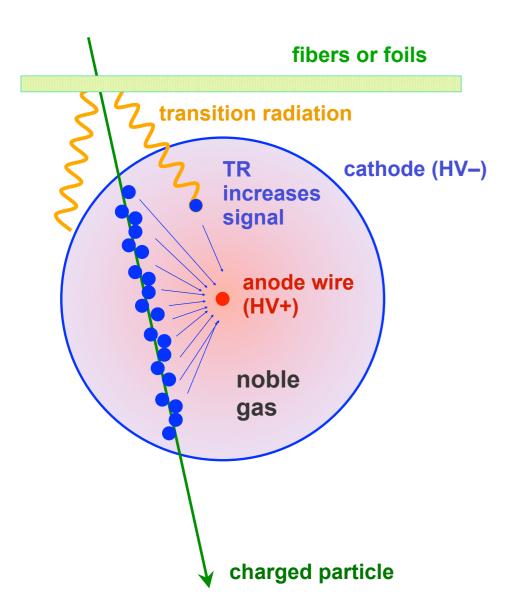
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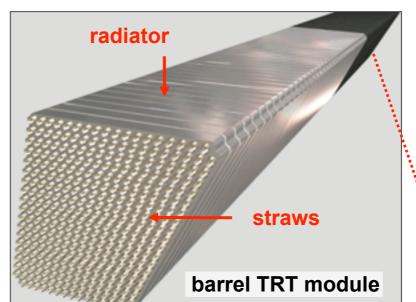
electrons radiate → higher signal PID info by counting high-threshold hits

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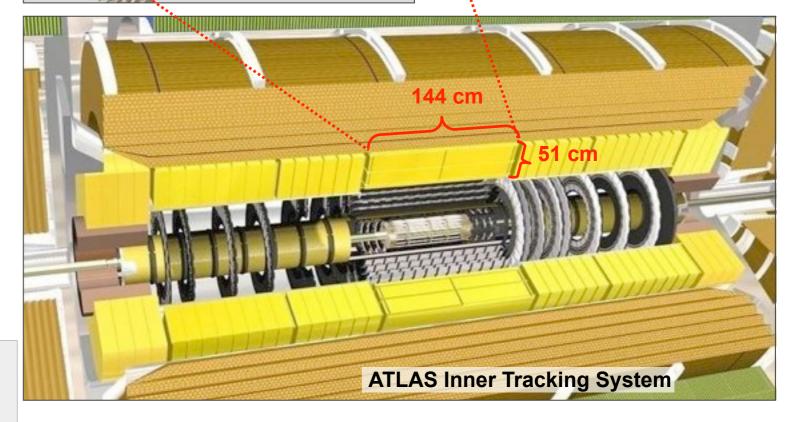


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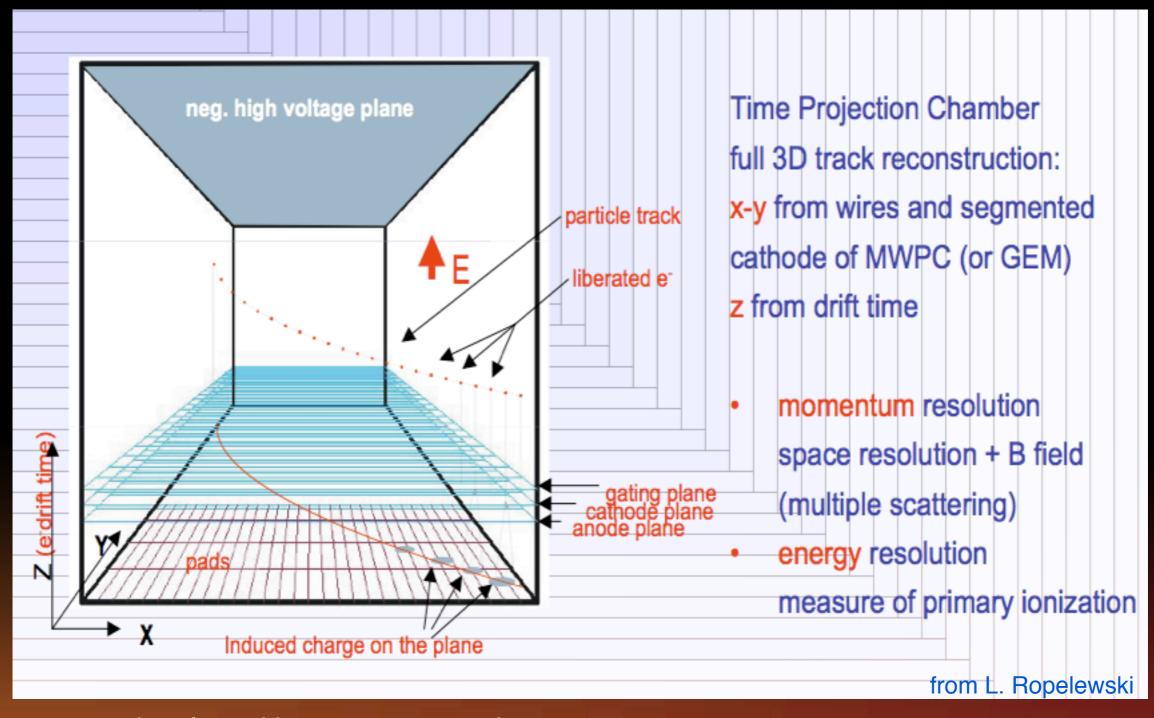


total: 370k straws barrel ($|\eta|$ < 0.7): 36 r- ϕ measurements / track resolution ~130 μ m / straw

14 end-cap wheels (|η| < 2.1): 40 or less *z-*φ points



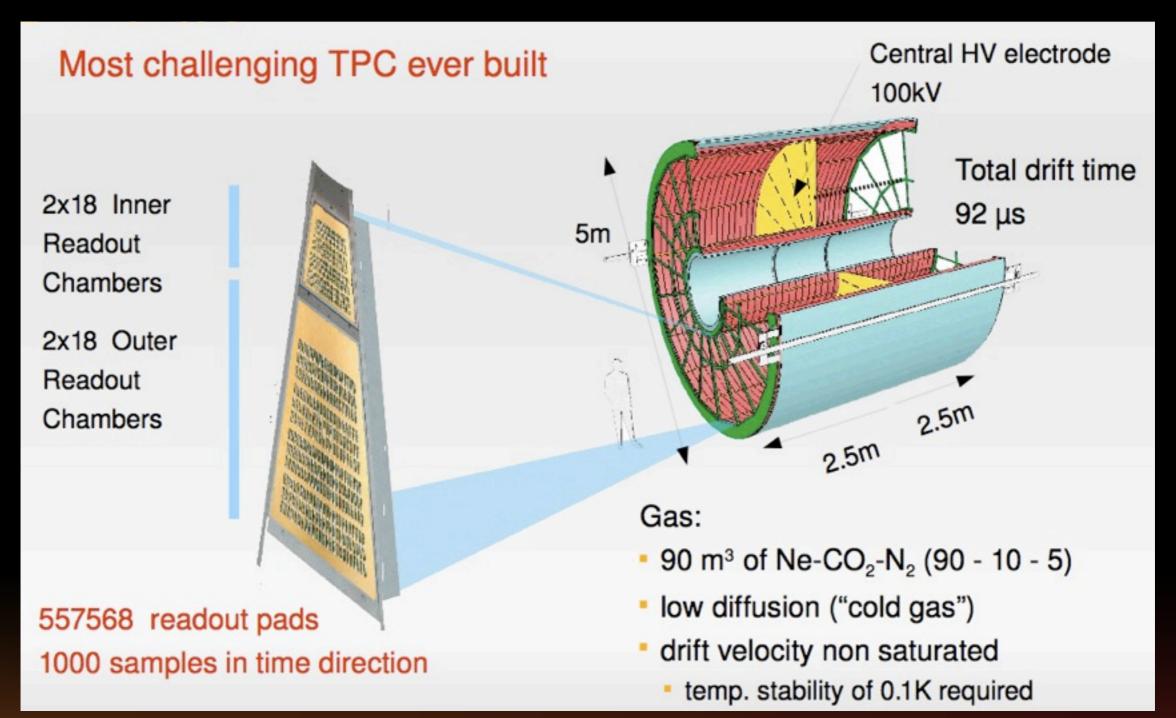
Time Projection Chambers





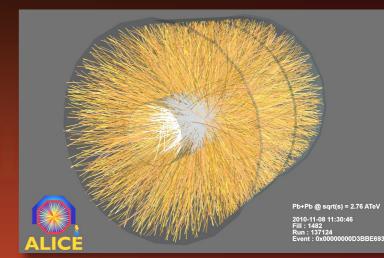
⇒ long drift times (\approx 40 µs), thus rate limitations and very good gas quality required





- → ALICE data taking rate 1 kHz in pp
- → few 100 Hz in Pb Pb

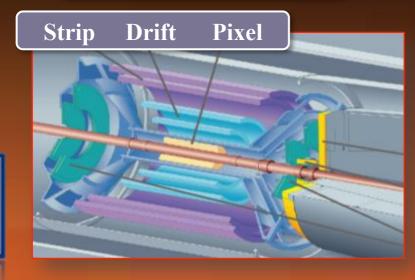


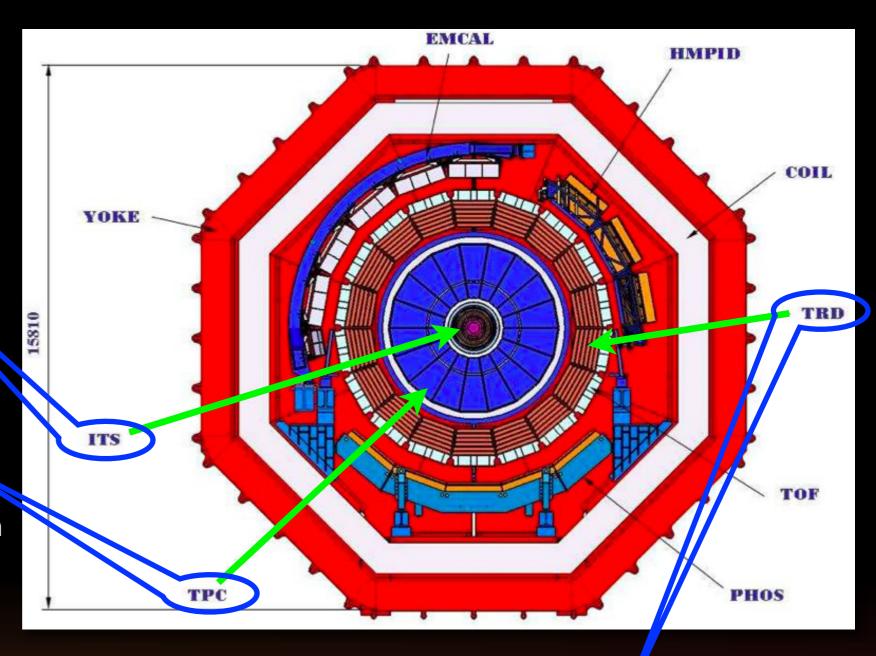


ALICE Tracking

- → ITS: 6 layers
 - 2 Pixels
 - 2 silicon drift detectors
 - 2 double sided strips
- **→** Time Projection Chamber
 - large volume gas detector with central electrode
 - MWPC with cathode pad readout in end plates
 - very good two-track resolution
 - very low material in active region

ITS: 3 different silicon detector technologies





- **→** Transition Radiation Detector
 - electron ID, and improves momentum resolution
 - outer radius 3.7m
- → installed in L3 magnet
 - lower B field (0.5 T), larger R



Comparison of Barrel Tracker Layouts

P.Wells	ALICE	ATLAS	CMS
R inner	3.9 cm	5.0 cm	4.4 cm
R outer	3.7 m	1.1 m	1.1 m
Length	5 m	5.4 m	5.8 m
η range	0.9	2.5	2.5
B field	0.5 T	2 T	4 T
Total X ₀ near η=0	0.08 (ITS) + 0.035 (TPC) + 0.234 (TRD)	0.3	0.4
Power	6 kW (ITS)	70 kW	60 kW
rφ resolution near outer radius	~ 800 μm TPC ~ 500 μm TRD	130 μm per TRT straw	35 μm per strip layer
p _T resolution at 1GeV and at 100 GeV	0.7% 3% (in pp)	1.3% 3.8%	0.7% 1.5%



⇒ p_T resolution is 0.35% at 1 GeV, 0.55% at 100 GeV for good mass resolution



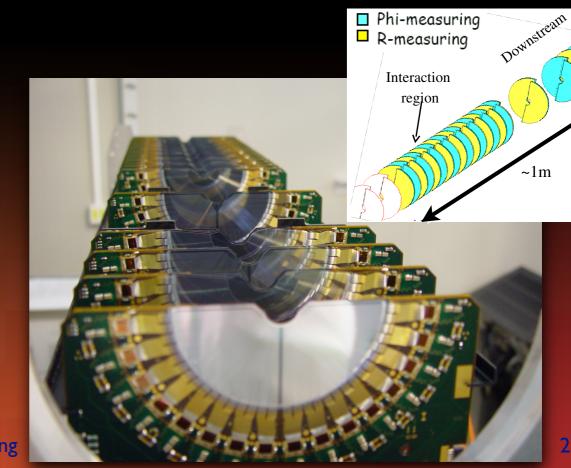
Summary of Pixel Barrel Layouts

P.Wells	ALICE	ATLAS	CMS
Radii (mm)	39 – 76	50.5 - 88.5 - 122.5	44 – 73 – 102
Pixel size $r\phi \times z$ (μm^2)	50 x 425	40 x 400	100 x 150
Thickness (μm)	200	250	285
Resolution <i>r</i> φ / <i>z</i> (μm)	12 / 100	10 / 115	~15-20
Channels (million)	9.8	80.4	66
Area (m²)	0.2	1.8	1

• LHCb VELO

- → forward geometry strip detector with 42 stations along, inner radius of 7 mm
- → moves close to beam when conditions are stable





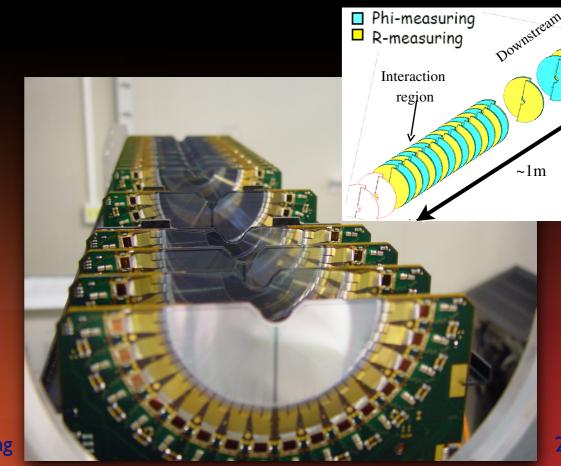
Summary of Pixel Barrel Layouts

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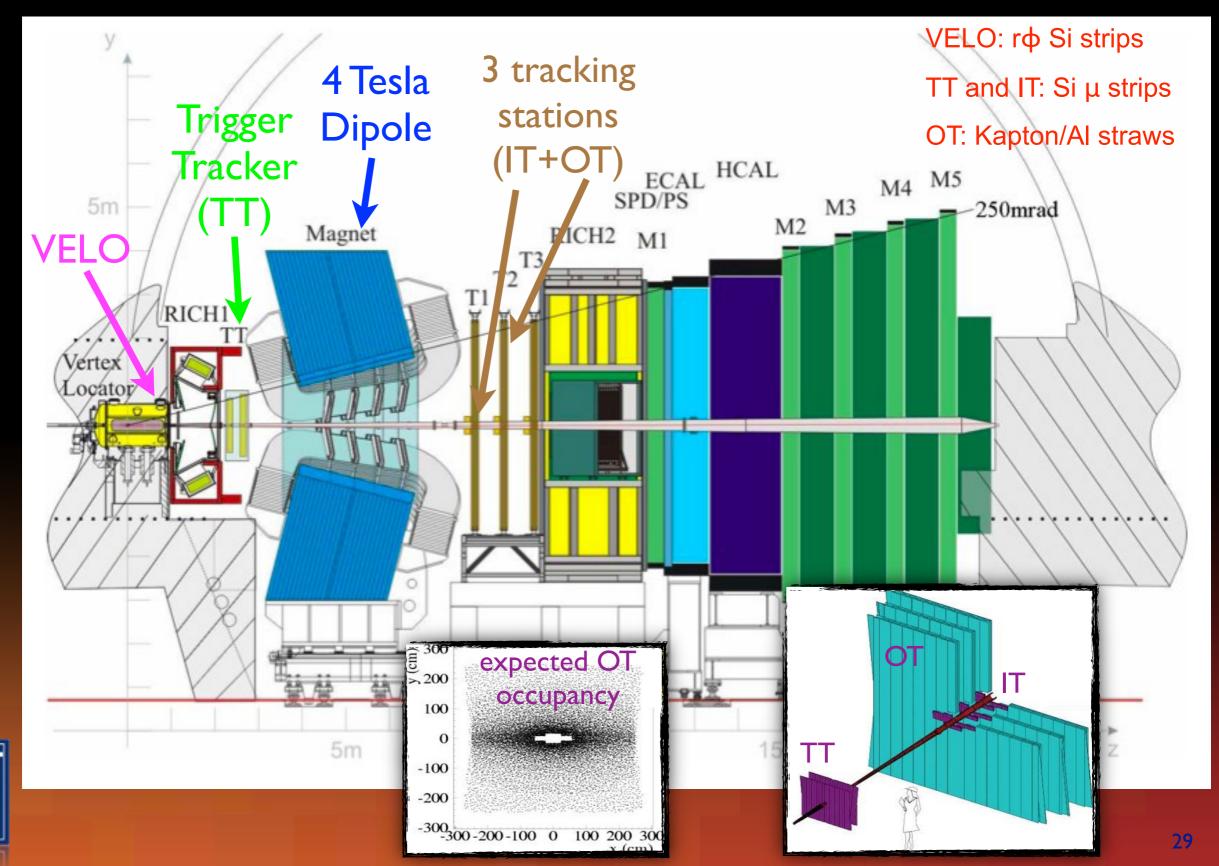
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LHCb Tracking





Let's Summarize

- discussed physics of particles in material
- in this lecture I discussed tracking detectors
 - → main design choices and constraints
 - → silicon and drift tube detectors
 - → LHC tracking detector layouts
- next I will discuss track reconstruction

